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April 1st, 2010 Renesas Electronics Corporation

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SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK3116 is N-channel DMOS FET device that features a low gate charge and excellent switching characteristics, and designed for high voltage applications such as switching power supply, AC adapter.

FEATURES

- •Low gate charge
- $Q_G = 26 \text{ nC TYP.}$ (ID = 7.5 A, VDD = 450 V, VGS = 10 V)
- •Gate voltage rating ±30 V
- •Low on-state resistance

 $R_{DS(on)} = 1.2 \Omega MAX. (V_{GS} = 10 V, I_{D} = 3.75 A)$

Avalanche capability ratings

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK3116	TO-220AB
2SK3116-S	TO-262
2SK3116-ZJ	TO-263

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vgs = 0 V)	VDSS	600	V
Gate to Source Voltage (Vps = 0 V)	Vgss	±30	V
Drain Current (DC)	ID(DC)	±7.5	Α
Drain Current (pulse) Note1	ID(pulse)	±30	Α
Total Power Dissipation (T _A = 25°C)	P _{T1}	1.5	W
Total Power Dissipation (Tc = 25°C)	P _{T2}	70	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note2	las	7.5	Α
Single Avalanche Energy Note2	Eas	37.5	mJ
Diode Recovery dv/dt Note3	dv/dt	3.5	V/ns

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

- 2. Starting Tch = 25°C, VDD = 150 V, Rg = 25 Ω , Vgs = 20 \rightarrow 0 V
- **3.** If ≤ 3.0 A, V_{clamp} = 600 V, di/dt ≤ 100 A/ μ s, T_A = 25°C

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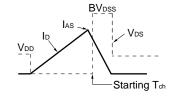


ELECTRICAL CHARACTERISTICS (TA = 25°C)

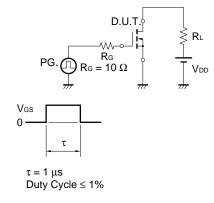
CHRACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	Ipss	Vps = 600 V, Vgs = 0 V			100	μΑ
Gate Leakage Current	Igss	Vgs = ±30 V, Vps = 0 V			±100	nA
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	2.5		3.5	V
Forward Transfer Admittance	y _{fs}	V _{DS} = 10 V, I _D = 3.75 A	2.0			S
Drain to Source On-state Resistance	RDS(on)	Vgs = 10 V, Ip = 3.75 A		0.9	1.2	Ω
Input Capacitance	Ciss	V _{DS} = 10 V		1100		pF
Output Capacitance	Coss	Vgs = 0 V		200		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		20		pF
Turn-on Delay Time	td(on)	V _{DD} = 150 V, I _D = 3.75 A		18		ns
Rise Time	tr	Vgs = 10 V		15		ns
Turn-off Delay Time	td(off)	$R_G = 10 \Omega$		50		ns
Fall Time	tf	R _L = 50 Ω		15		ns
Total Gate Charge	QG	V _{DD} = 450 V		26		nC
Gate to Source Charge	Qgs	Vgs = 10 V		6		nC
Gate to Drain Charge	Q _{GD}	ID = 7.5 A		10		nC
Body Diode Forward Voltage	V _{F(S-D)}	IF = 7.5 A, VGS = 0 V		1.0		V
Reverse Recovery Time	Trr	IF = 7.5 A, VGS = 0 V		1.6		μs
Reverse Recovery Charge	Qrr	di/dt = 50 A/ μs		7.6		μC

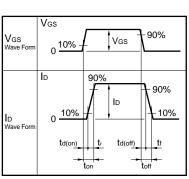
TEST CIRCUIT 1 AVALANCHE CAPABILITY

$\begin{array}{c} \text{D.U.T.} \\ \text{RG} = 25 \ \Omega \\ \text{VGS} = 20 \rightarrow 0 \ V \end{array} \begin{array}{c} \text{D.U.T.} \\ \text{S} \\ \text{D.U.T.} \\ \text{NOD} \\$



TEST CIRCUIT 2 SWITCHING TIME

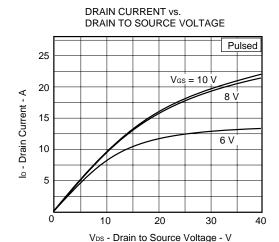


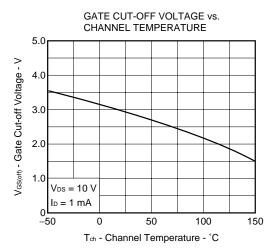


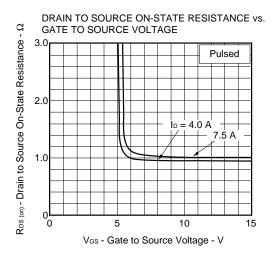
TEST CIRCUIT 3 GATE CHARGE



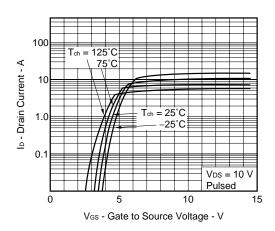
TYPICAL CHARACTERISTICS (TA = 25°C)



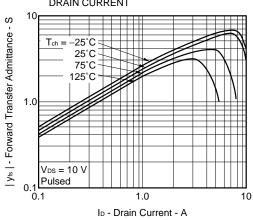


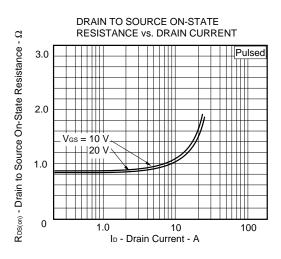


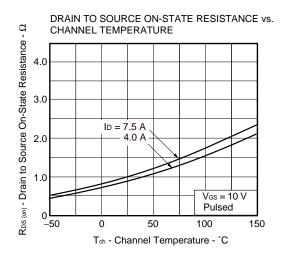
FORWARD TRANSFER CHARACTERISTICS

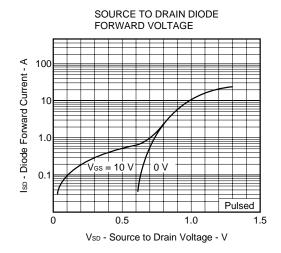


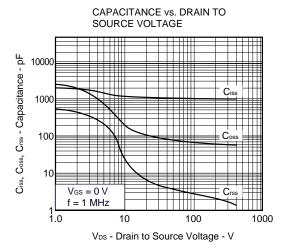
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

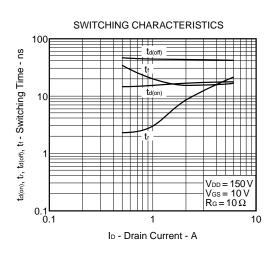


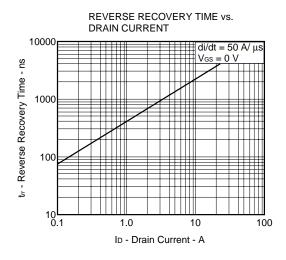


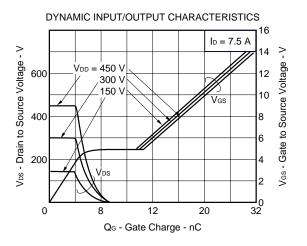


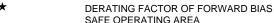






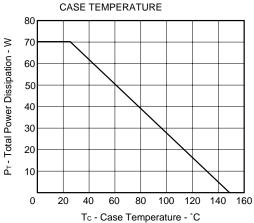




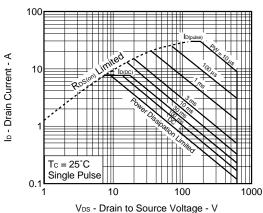




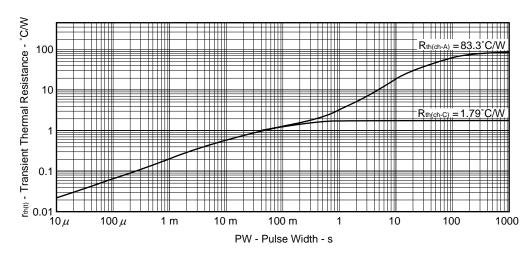
TOTAL POWER DISSIPATION vs.

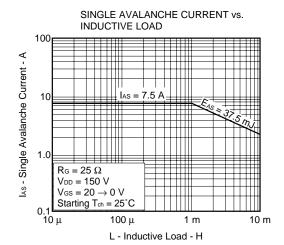


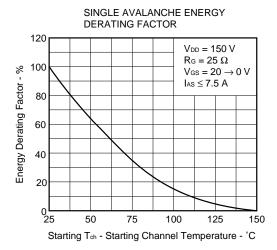
FORWARD BIAS SAFE OPERATING AREA



TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



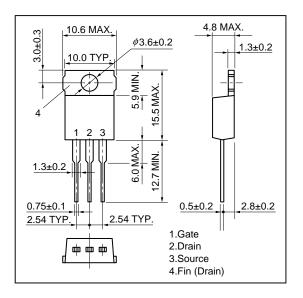




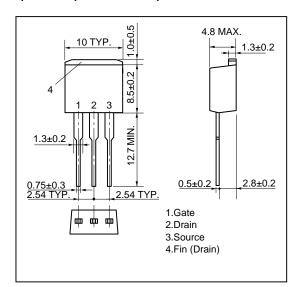


★ PACKAGE DRAWINGS (Unit: mm)

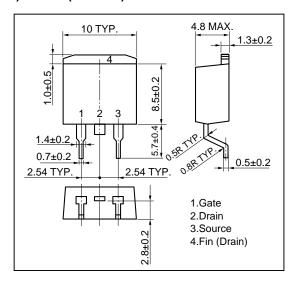
1) TO-220AB (MP-25)



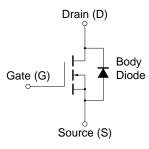
2) TO-262 (MP-25 Fin Cut)



3) TO-263 (MP-25ZJ)



EQUIVALENT CIRCUIT



Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.



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